

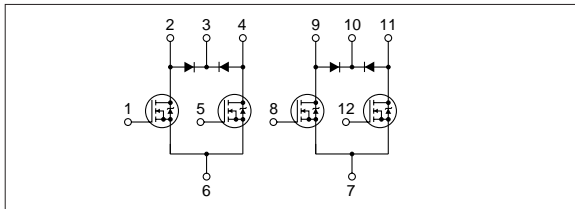
Absolute maximum ratings

($T_a=25^\circ\text{C}$)

Symbol	Ratings	Unit
V_{DSS}	100	V
V_{GSS}	± 10	V
I_D	± 5	A
$I_{D(pulse)}$	± 10 ($PW \leq 1\text{ms}$)	A
E_{AS}^*	32	mJ
I_F	5 ($PW \leq 0.5\text{ms}$, $D_u \leq 25\%$)	A
I_{FSM}	10 ($PW \leq 10\text{ms}$, Single pulse)	A
V_R	120	V
P_T	4 ($T_a=25^\circ\text{C}$, with all circuits operating, without heatsink)	W
	28 ($T_c=25^\circ\text{C}$, with all circuits operating, with infinite heatsink)	W
θ_{j-a}	31.2 (Junction-Air, $T_a=25^\circ\text{C}$, with all circuits operating)	$^\circ\text{C}/\text{W}$
θ_{j-c}	4.46 (Junction-Case, $T_c=25^\circ\text{C}$, with all circuits operating)	$^\circ\text{C}/\text{W}$
T_{ch}	150	$^\circ\text{C}$
T_{stg}	-40 to +150	$^\circ\text{C}$

*: $V_{DD}=20\text{V}$, $L=2\text{mH}$, $I_D=5\text{A}$, unclamped, see Fig. E on page 15.

Equivalent circuit diagram



Electrical characteristics

($T_a=25^\circ\text{C}$)

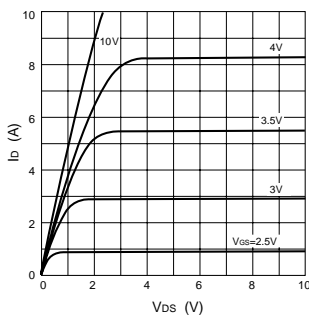
Symbol	Specification			Unit	Conditions
	min	typ	max		
$V_{(BR)DSS}$	100			V	$I_D=250\mu\text{A}$, $V_{GS}=0\text{V}$
I_{GSS}			± 500	nA	$V_{GS}=\pm 10\text{V}$
I_{DSS}			250	μA	$V_{DS}=100\text{V}$, $V_{GS}=0\text{V}$
V_{TH}	1.0		2.0	V	$V_{DS}=10\text{V}$, $I_D=250\mu\text{A}$
$R_{DS(ON)}$		3.1	4.5	S	$V_{DS}=10\text{V}$, $I_D=5\text{A}$
		0.27	0.30	Ω	$V_{GS}=10\text{V}$, $I_D=2.5\text{A}$
		0.38	0.41	Ω	$V_{GS}=4\text{V}$, $I_D=2.5\text{A}$
C_{iss}	470			pF	$V_{DS}=25\text{V}$, $f=1.0\text{MHz}$, $V_{GS}=0\text{V}$
C_{oss}	130			pF	$V_{GS}=0\text{V}$
t_{on}	70			ns	$I_D=5\text{A}$, $V_{DD}=50\text{V}$, $V_{GS}=5\text{V}$, see Fig. 3 on page 16.
t_{off}	50			ns	
V_{SD}	1.2	2.0		V	$I_{SD}=5\text{A}$, $V_{GS}=0\text{V}$
t_{rr}	330			ns	$I_{SD}=\pm 100\text{mA}$

Diode for flyback voltage absorption (1 circuit)

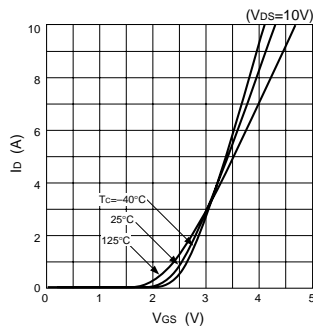
Symbol	Specification			Unit	Conditions
	min	typ	max		
V_R	120			V	$I_R=10\mu\text{A}$
V_F		1.0	1.2	V	$I_F=1\text{A}$
I_R			10	μA	$V_R=120\text{V}$
t_{rr}		100		ns	$I_F=\pm 100\text{mA}$

Characteristic curves

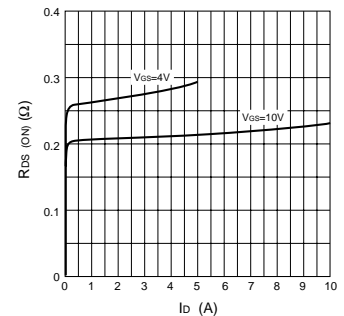
I_D - V_{DS} Characteristics (Typical)



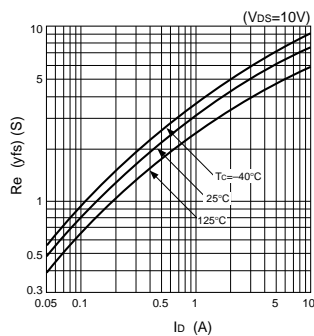
I_D - V_{GS} Characteristics (Typical)



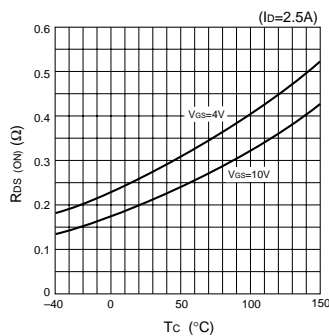
$R_{DS(ON)}$ - I_D Characteristics (Typical)



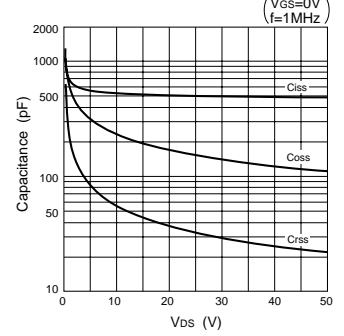
$R_{e(yfs)}$ - I_D Characteristics (Typical)



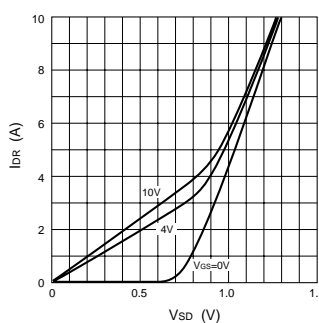
$R_{DS(ON)}$ - T_C Characteristics (Typical)



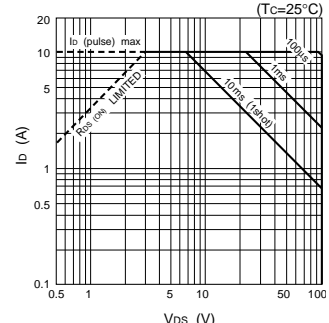
Capacitance- V_{DS} Characteristics (Typical)



I_{DR} - V_{SD} Characteristics (Typical)



Safe Operating Area (SOA)



P_T - T_a Characteristics

